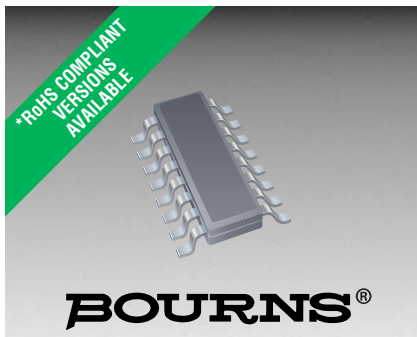




Features

- Lead free device (RoHS Compliant*)
- Protects 8 lines
- Unidirectional & bidirectional configurations
- ESD protection

Applications

- Audio/video inputs
- RS-232, RS-422 & RS-423 data lines
- Portable electronics
- Medical sensors

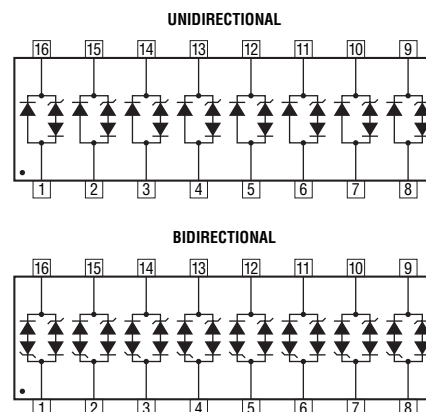
CDNBS16-T03~T36C – TVS Diode Array Series

General Information

The markets of portable communications, computing and video equipment are challenging the semiconductor industry to develop increasingly smaller electronic components.

Bourns offers Transient Voltage Suppressor Array diodes for surge and ESD protection applications, in 16 Lead Narrow Body SOIC package size format. The Transient Voltage Suppressor Array series offer a choice of voltage types ranging from 3 V to 36 V in unidirectional and bidirectional configurations. Bourns® Chip Diodes conform to JEDEC standards, are easy to handle on standard pick and place equipment and their flat configuration minimizes roll away.

The Bourns® device will meet IEC 61000-4-2 (ESD), IEC 61000-4-4 (EFT) and IEC 61000-4-5 (Surge) requirements.



Thermal Characteristics (@ $T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	Max.	Unit
Operating Temperature	T_J	-55 to +150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	CDNBS16-														Unit
		Uni-	Bi-	Uni-	Bi-	Uni-	Bi-	Uni-	Bi-	Uni-	Bi-	Uni-	Bi-	Uni-	Bi-	
		T03	T03C	T05	T05C	T08	T08C	T12	T12C	T15	T15C	T24	T24C	T36	T36C	
Minimum Breakdown Voltage @ 1 mA	V_{BR}	4.5		6.0		8.5		13.3		16.7		26.7		40.0		V
Working Peak Voltage	V_{WM}	3.0		5.0		8.0		12.0		15.0		24.0		36.0		V
Maximum Clamping Voltage V_C @ $I_P = 1\text{ A}^1$	V_C	8.0		9.8		13.4		19.0		25.5		40.0		53.0		V
Maximum Clamping Voltage @ 8/20 μs V_C @ I_{PP}^1	V_C	23 V @ 43 A		24 V @ 42 A		26 V @ 30 A		33 V @ 21 A		39 V @ 15 A		57 V @ 10 A		72 V @ 7 A		V
Maximum Leakage Current @ V_{WM}	I_D	125		20		10		2		2		2		2		μA
Maximum Capacitance @ 0 V, 1 MHz	$C_{j(SD)}$	15														pF
Temperature Coefficient of V_{BR}		-3		3		9		16		17		26		36		mV/ $^\circ\text{C}$
Peak Pulse Power (tp = 8/20 μs) ²	P_{PP}	500														W
Forward Voltage @ 100 mA, 300 μs – Square Wave ³	V_F	1.5														V

Notes:

1. See Pulse Wave Form.
2. See Peak Pulse Power vs. Pulse Time.
3. Only applies to unidirectional devices.
4. Part numbers with a "C" suffix are bidirectional devices, i.e., CDNBS16-T03C.

*RoHS Directive 2002/95/EC Jan 27, 2003 including Annex.

Specifications are subject to change without notice.

Customers should verify actual device performance in their specific applications.

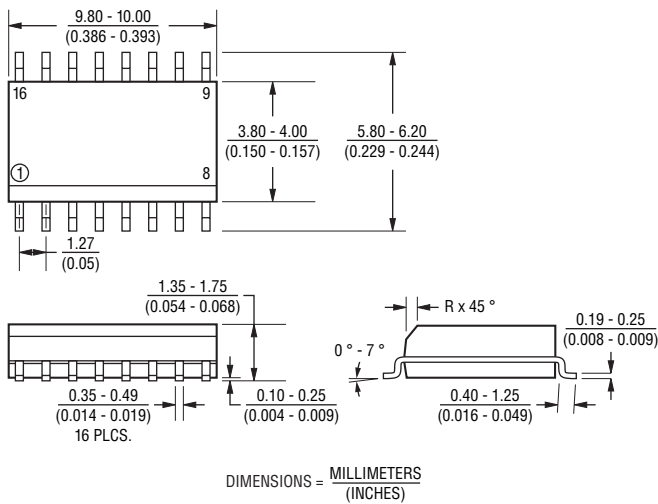
CDNBS16-T03~T36C – TVS Diode Array Series

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Mechanical Characteristics

This is a molded JEDEC Narrow Body SO-16 package with lead free 100 % Sn plating on the lead frame. It weighs approximately 30 mg and has a flammability rating of UL 94V-0.

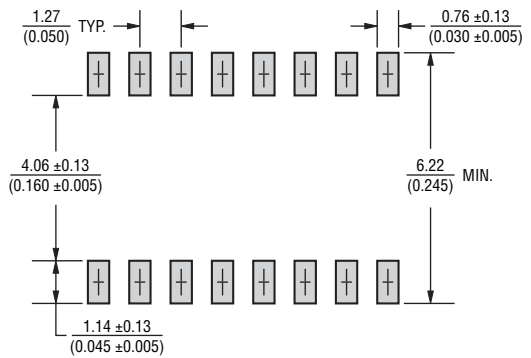
Product Dimensions



Typical Part Marking

CDNBS16-T03	CDNBS16-T03
CDNBS16-T05	CDNBS16-T05
CDNBS16-T08	CDNBS16-T08
CDNBS16-T12	CDNBS16-T12
CDNBS16-T15	CDNBS16-T15
CDNBS16-T24	CDNBS16-T24
CDNBS16-T36	CDNBS16-T36
CDNBS16-T03C	CDNBS16-T03C
CDNBS16-T05C	CDNBS16-T05C
CDNBS16-T08C	CDNBS16-T08C
CDNBS16-T12C	CDNBS16-T12C
CDNBS16-T15C	CDNBS16-T15C
CDNBS16-T24C	CDNBS16-T24C
CDNBS16-T36C	CDNBS16-T36C

Recommended Footprint



How To Order

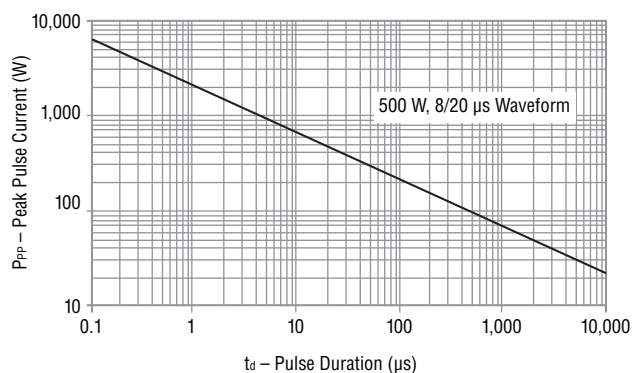
Common Code	CD	NBS16	-	T	03	C
Chip Diode						
Package						
NBS16 = 16L NSOIC Package						
Model						
T = Transient Voltage Suppressor						
Working Peak Reverse Voltage						
03 = 3 V _{RWM} (Volts)						
Suffix						
C = Bidirectional Diode						

CDNBS16-T03~T36C – TVS Diode Array Series

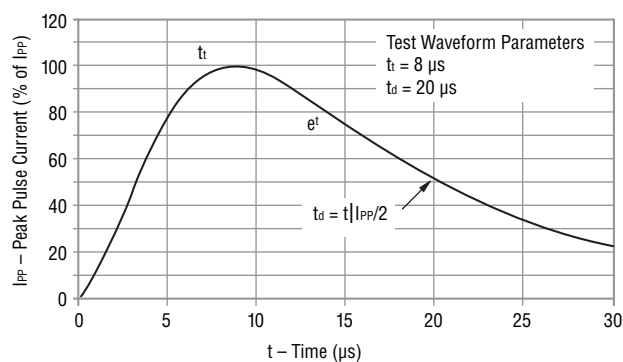
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Performance Graphs

Peak Pulse Power vs Pulse Time

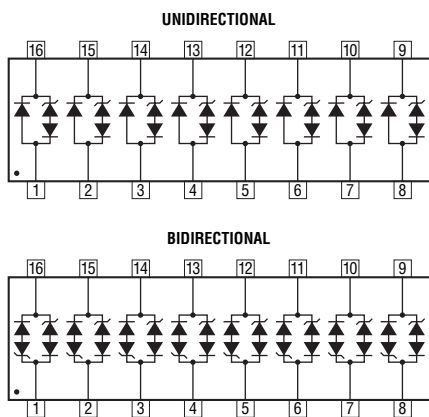


Pulse Wave Form

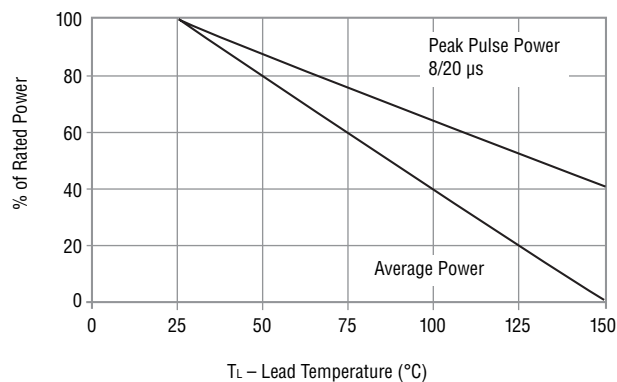


Block Diagram

The device block diagrams below include the pin names and basic electrical connections associated with each channel.



Power Derating Curve



Device Pinout

Pin	Function	Pin	Function
1	GND	9	I/O 1
2	GND	10	I/O 2
3	GND	11	I/O 3
4	GND	12	I/O 4
5	GND	13	I/O 5
6	GND	14	I/O 6
7	GND	15	I/O 7
8	GND	16	I/O 8

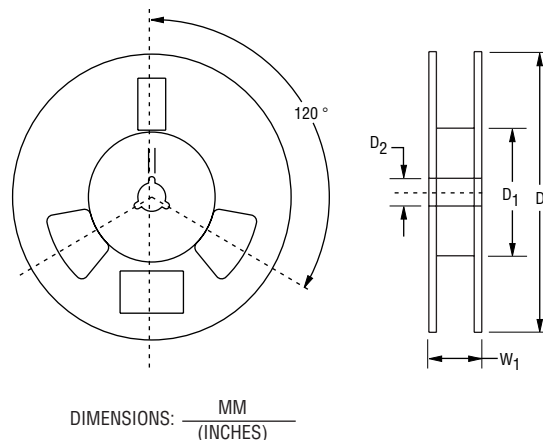
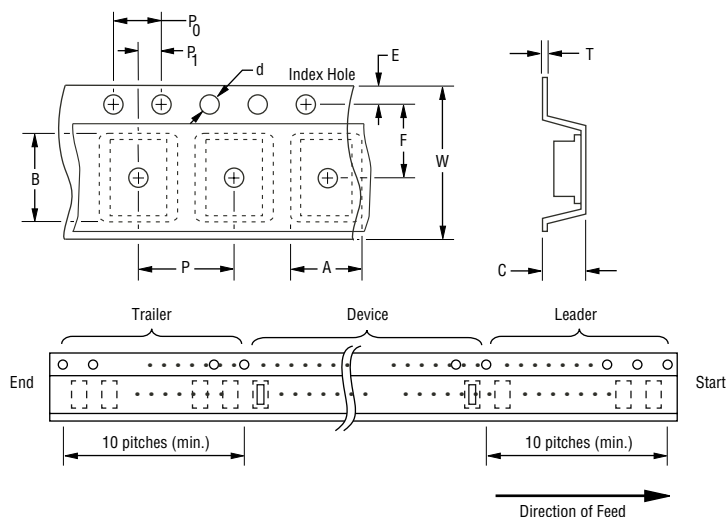
Specifications are subject to change without notice.
Customers should verify actual device performance in their specific applications.

CDNBS16-T03~T36C – TVS Diode Array Series

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Packaging Specifications

The product will be dispensed in Tape and Reel format (see diagram below).



Devices are packed in accordance with EIA standard RS-481-A.

Item	Symbol	NSOIC 16L
Carrier Width	A	$\frac{6.7 \pm 0.10}{(0.264 \pm 0.004)}$
Carrier Length	B	$\frac{10.5 \pm 0.10}{0.413 \pm 0.004}$
Carrier Depth	C	$\frac{2.10 \pm 0.10}{0.083 \pm 0.004}$
Sprocket Hole	d	$\frac{1.55 \pm 0.05}{(0.061 \pm 0.002)}$
Reel Outside Diameter	D	$\frac{330}{(12.992)}$
Reel Inner Diameter	D ₁	$\frac{80.0}{(3.1500)} \text{ MIN.}$
Feed Hole Diameter	D ₂	$\frac{13.0 \pm 0.20}{(0.512 \pm 0.008)}$
Sprocket Hole Position	E	$\frac{1.75 \pm 0.10}{(0.069 \pm 0.004)}$
Punch Hole Position	F	$\frac{3.50 \pm 0.05}{(0.138 \pm 0.002)}$
Punch Hole Pitch	P	$\frac{8.00 \pm 0.10}{(0.315 \pm 0.004)}$
Sprocket Hole Pitch	P ₀	$\frac{4.00 \pm 0.10}{(0.157 \pm 0.004)}$
Embossment Center	P ₁	$\frac{2.00 \pm 0.05}{(0.079 \pm 0.002)}$
Overall Tape Thickness	T	$\frac{0.20 \pm 0.10}{(0.008 \pm 0.004)}$
Tape Width	W	$\frac{16.00 \pm 0.20}{(0.630 \pm 0.008)}$
Reel Width	W ₁	$\frac{18.4}{(0.724)} \text{ MAX.}$
Quantity per Reel	-	2500

REV. 07/11

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Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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